

Visible Light Photo Reflector

Product No: MTRS1070

Peak Emission Wavelength: 700nm

The 700nm reflective sensor consists of a 700nm visible emitter and high sensitivity photo transistor in the same package. The black molded housing reduces the effect of external ambient light. Custom emitter/detectors are available.

FEATURES

- > High Reliability
- > Compact (Ф4.0)
- > Short Detection Distance Optimum 0.5-1.5mm

APPLICATIONS

- > Card Reader
- > Bar-code Reader
- > Edge Sensing / Money-bill Reader



Absolute Maximum	Ratings (T	a=25°C)		Pb. 4
ITEMS	SYMBOL	RATINGS	UNIT	lead-free ROHS
Forward Current (LED)	IF	50	mA	
Pulse Forward Current (LED)*1	IFP	0.5	A	
Reverse Voltage (LED)	VR	4	V	
Power Dissipation (LED)	PD	100	mW	
Collector-Emitter Voltage (PT)	Vce	20	V	
Emitter-Collector Voltage (PT)	Vec	5	V	
Collector Current (PT)	Ic	50	mA	
Collector Power Dissipation (PT)	PC	75	mW	
Total Power Dissipation	Ptot	100	mW	
Operating Temperature Range	Topr	-20 ~ +80	°C	*1: Tw=10µsec, T=10msec.

Electrical & Optical Characteristics (Ta = 25°C)									
ITEMS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT			
Forward Voltage	VF	IF=20mA		1.8	2.3	V			
Reverse Current	IR	VR=4V			10	μΑ			
Peak Emission Wavelength	λр	IF=20mA		700		nm			
Spectral Line Half Width	Δλ	IF=20mA		25		nm			
Dark Current (Iceo)	ID	Vce=10V			100	nA			
Output Current	lo	IF=20mA, Vce=2V, d=1mm *	180	500		μΑ			
Cross-talk Current	lx	IF=20mA, Vce=2V			200	nA			
Rise Time (10 to 90%)	Tr	Vcc=5V, lo=0.1mA, RL=1KΩ		20		μS			
Fall Time (10 to 90%)	Tf	Vcc=5V, lo=0.1mA, RL=1KΩ		30		μS			
Lead Soldering Temperature*2	Tls				260	°C			

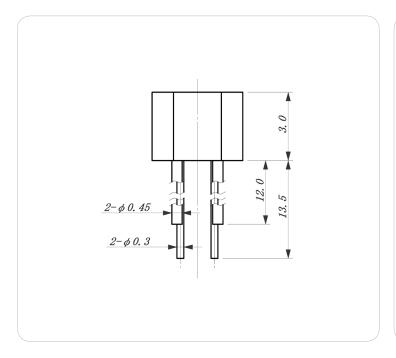
*1: Measured by reflecting with Aluminum evaporated mirror (d=1.00mm). *2: Time 5 Sec max, Position: Up to 3mm from the body.

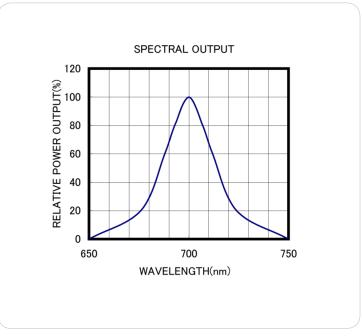
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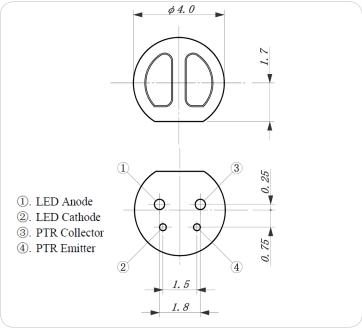


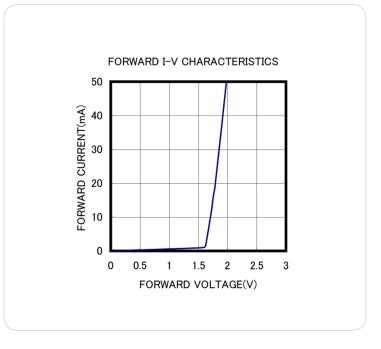


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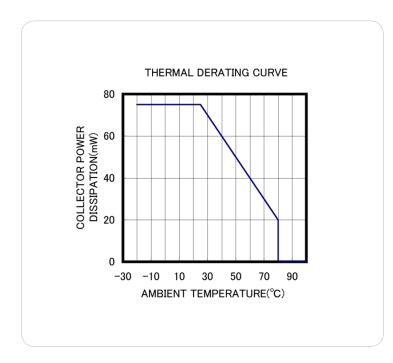


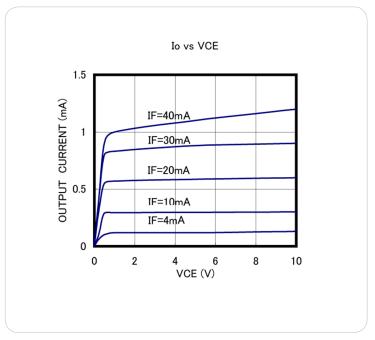


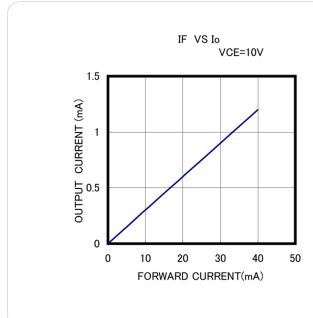


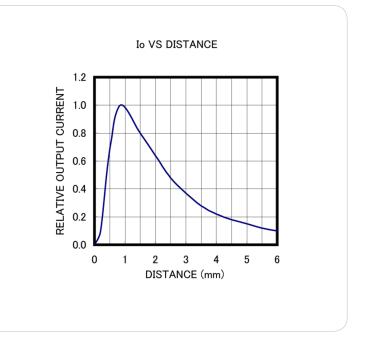
Unit: mm, Tolerance: ±0.2











The information contained herein is subject to change without notice.